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Properties of electron-doped high temperature superconductor $\text{Nd}_{2-x}\text{Ce}_x\text{CuO}_4$ Films deposited by TFA-MOD

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Superconducting materials with a high in-field critical current density (J_c) and a low-cost process are required for superconducting applications such as nuclear magnetic resonance equipment, generators, and energy storage devices. The in-field J_c is strongly related to not only the vortex pinning but also crystallinity and critical temperature (T_c). The trifluoroacetates metal organic deposition (TFA-MOD) process is effective process to crystalize the high crystallinity film and introduce the artificial pinning centers. We reported that the TFA-MOD derived hole-doped high temperature superconductor (HTS) ($\text{Y}_{0.77}\text{Gd}_{0.23}\text{Ba}_2\text{Cu}_3\text{O}_y$) ((Y,Gd)BCO) film shows high in-field J_c due to high crystallinity and T_c even with the introduction of high density of adding artificial pinning centers [1]. Although electron-doped $\text{RE}_{2-x}\text{Ce}_x\text{CuO}_4$ (RECCO, RE = Nd, Pr, Eu...) is also high temperature superconductor, J_c in RECCO film has not yet been clarified.

In this work, we report that the structural and electrical properties of TFA-MOD derived $\text{Nd}_{2-x}\text{Ce}_x\text{CuO}_4$ (NCCO, $x = 0, 0.15$) films grown on the substrates with various lattice mismatch. The X-ray diffraction result shows that c -axis oriented NCCO films were grown on LaAlO_3 and DyScO_3 substrate. The c -axis oriented NCCO films show high crystallinity ($\Delta\omega \approx 0.14^\circ$). The ρ -T curve of the NCCO ($x = 0.15$) film on LaAlO_3 shows superconducting transition ($T_c \approx 9$ K). This T_c value is lower than that of the bulk value (~ 24 K). The low T_c could be attributed to the lattice mismatch between the NCCO and the LaAlO_3 substrate (-4.0% , compressive strain). The structural and electrical properties of NCCO films grown on substrates with various lattice mismatch will be reported.

[1] M. Miura et al., NPG Asia Materials 9, (2017) e447

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